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In re Application of MAR 21 2001
TC 2600 MAIL ROOM
HANS U. SCHROEDER ET AL

Atty. Docket

PHN 17,073

Serial No.: 09/389,826

Art Unit: 2811

Filed: September 3, 1999

Examiner: O. NADAV

Title: SEMICONDUCTOR DEVICE

AMENDMENT

Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

In response to the Office Action dated December 18, 2000,
Applicants submit the following amendments and remarks.

IN THE CLAIMS

Please amend Claims 1 and 4 as follows:

1. A semiconductor device having a semiconductor body which on a surface comprises an integrated circuit containing protection means for protection against electrostatic discharge (ESD), the means being a compound element of an SCR and a gated diode, the protection means being provided in a surface area of a first conductivity type having a single well of a second, opposite, conductivity type, in which area